

SANYO Semiconductors DATA SHEET

2SJ664 — General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 4V drive.
- · Motor drive, DC / DC converter.
- · Avalanche resistance guarantee.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-100	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		-17	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-68	Α
Allowable Power Dissipation	D-		1.65	W
	PD	Tc=25°C	50	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *1	EAS		38	mJ
Avalanche Current *2	IAV		-17	Α

Note: *1 V_{DD}=30V, L=200μH, I_{AV}=-17A

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			l lait
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =-1mA, V _G S=0V	-100			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-100V, V _{GS} =0V			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} = ±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-8A	9	15		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =-8A, V _G S=-10V		102	136	mΩ
	R _{DS} (on)2	I _D =-8A, V _G S=-4V		138	193	mΩ

Marking: J664 Continued on next page.

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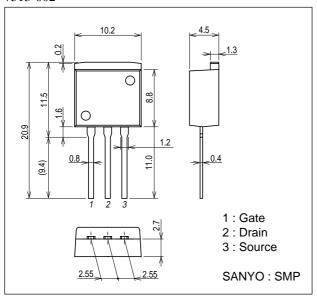
^{*2} L≤200µH, Single pulse

Continued from preceding page.

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss	V _{DS} =-20V, f=1MHz		2090		pF
Output Capacitance	Coss	V _{DS} =-20V, f=1MHz		155		pF
Reverse Transfer Capacitance	Crss	VDS=-20V, f=1MHz		108		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		17		ns
Rise Time	t _r	See specified Test Circuit.		105		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		185		ns
Fall Time	tf	See specified Test Circuit.		98		ns
Total Gate Charge	Qg	V _{DS} =-50V, V _{GS} =-10V, I _D =-17A		41		nC
Gate-to-Source Charge	Qgs	VDS=-50V, VGS=-10V, ID=-17A		7		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =-50V, V _{GS} =-10V, I _D =-17A		9		nC
Diode Forward Voltage	V _{SD}	I _S =-17A, V _{GS} =0V		-0.93	-1.2	V

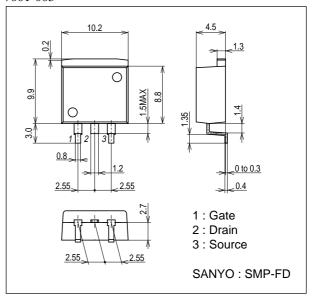
Package Dimensions

unit : mm 7513-002

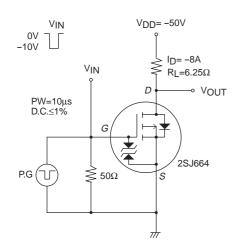


Package Dimensions

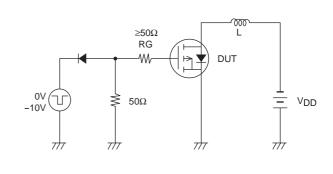
unit : mm 7001-003

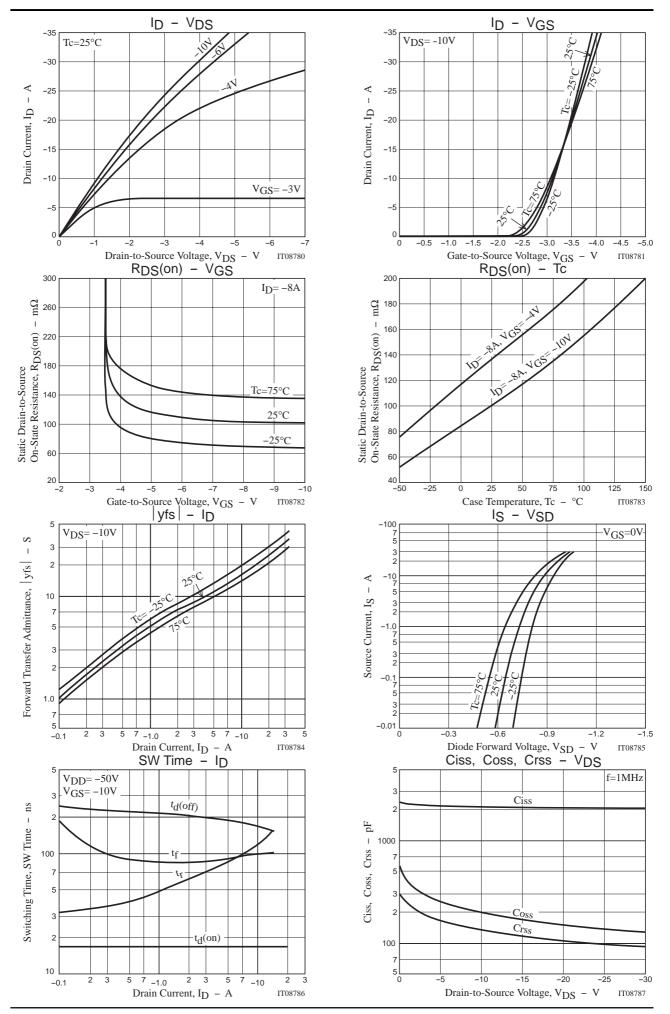


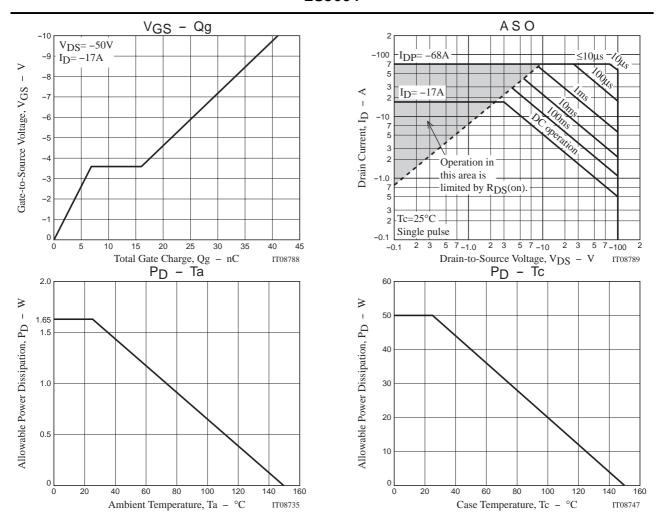
Switching Time Test Circuit



Avalanche Resistance Test Circuit







Note on usage: Since the 2SJ664 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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